EVERLIGHT

Technical Data Sheet

3mm Phototransistor T-1

PT204-6B-27

Features

- Fast response time
- High photo sensitivity
- Pb Free
- The product itself will remain within RoHS compliant version.

Descriptions

- PT204-6B-27 is a high speed and high sensitive NPN silicon phototransistor molded in a standard 3 mm package.
  Due to its black epoxy the device is sensitive to infrared radiation.

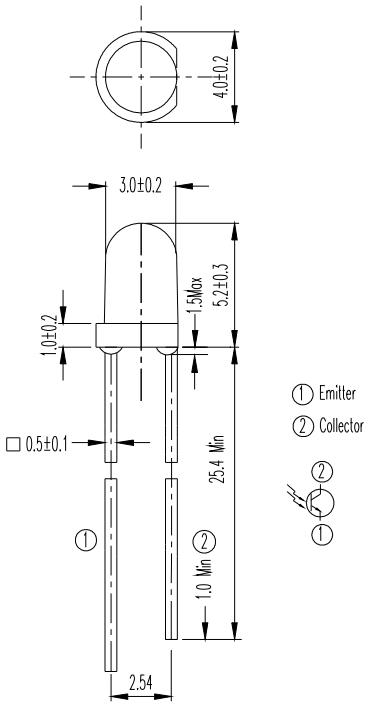
Applications

- Infrared applied system
- Camera
- Printer
- Cockroach catcher

Device Selection Guide

LED Part No.	Chip Material	Lens Color
PT	Silicon	Black

Package Dimensions



Notes: 1.All dimensions are in millimeters
2.Tolerances unless dimensions ±0.25mm

Absolute Maximum Ratings (Ta=25℃)

Parameter	Symbol	Rating	Units
Collector-Emitter Voltage	V_{CEO}	30	V
Emitter-Collector-Voltage	V_{ECO}	5	V
Collector Current	I_C	20	mA
Operating Temperature	Topr	-25 ~ +85℃	℃
Storage Temperature	Tstg	-40 ~ +100℃	℃
Lead Soldering Temperature	Tsol	260	℃
Power Dissipation at (or below) 25℃ Free Air Temperature	Pc	75	mW

Notes: *1:Soldering time≦5 seconds.

Electro-Optical Characteristics (Ta=25℃)

Parameter	Symbol	Condition	Min.	Typ.	Max.	Units
Collector – Emitter Breakdown Voltage	BV_{CEO}	I_C=100μA Ee=0mW/cm^2	30	---	---	V
Emitter-Collector Breakdown Voltage	BV_{ECO}	I_E=100μA Ee=0mW/cm^2	5	---	---	V
Collector-Emitter Saturation Voltage	$V_{CE)(sat)}$	I_C=2mA Ee=1mW/cm^2	---	---	0.4	V
Rise Time	t_r	V_{CE}=5V I_C=1mA RL=1000Ω	---	15	---	μS
Fall Time	t_f		---	15	---	
Collector Dark Current	I_{CEO}	Ee=0mW/cm^2 V_{CE}=20V	---	---	100	nA
On State Collector Current	$I_{C(on)}$	Ee=1mW/cm^2 V_{CE}=5V	1.77	---	5.07	mA
Wavelength of Peak Sensitivity	λp	---	---	940	---	nm
Rang of Spectral Bandwidth	$\lambda_{0.5}$	---	---	760-1100	---	nm

Rankings

Parameter	Symbol	Min	Max	Unit	Test Condition
J	$I_{C(ON)}$	1.77	3.61	mA	V_{CE}=5V Ee=1mW/c㎡
K		2.67	5.07		

Typical Electro-Optical Characteristics Curves

Fig.1Collector Power Dissipation vs. Ambient Temperature

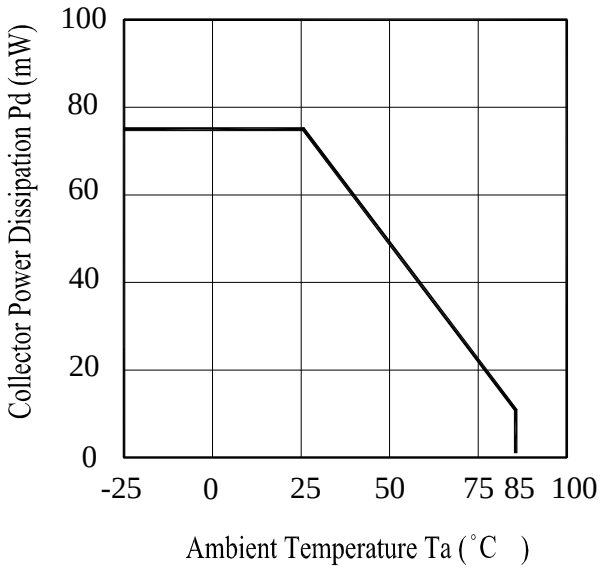


Fig.2 Spectral Sensitivity

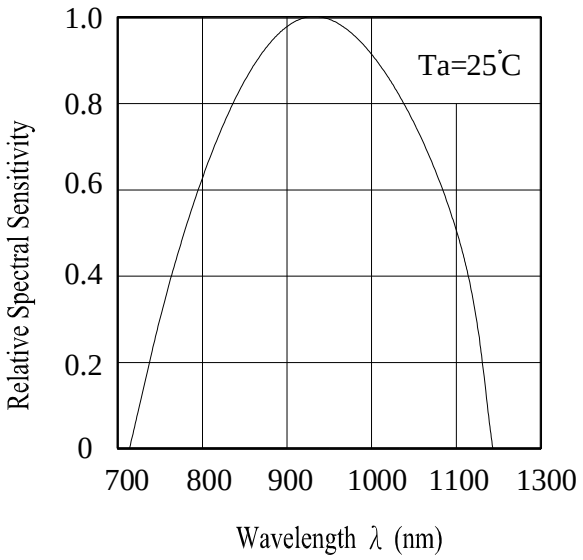


Fig.3 Relative Collector Current vs. Ambient Temperature

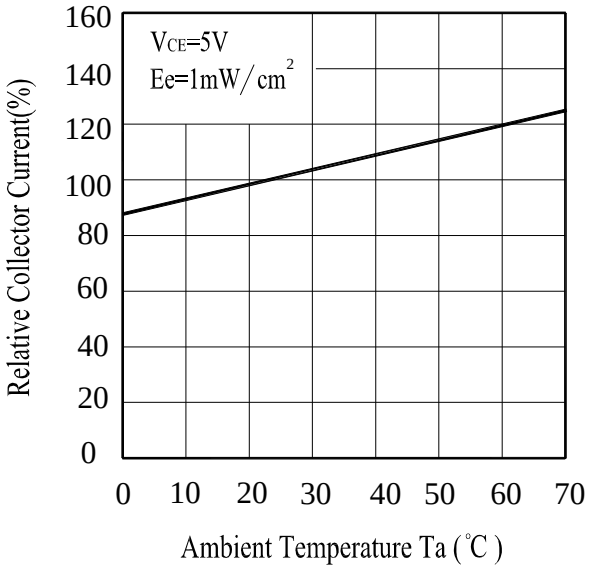
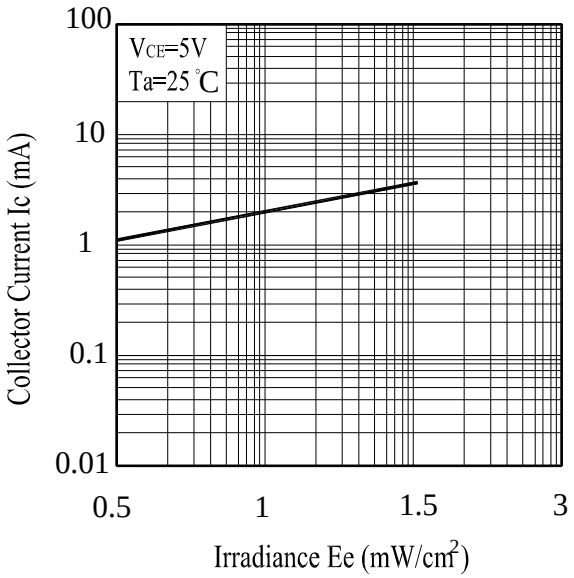


Fig.4 Collector Current vs. Irradiance



Typical Electro-Optical Characteristics Curves

Fig.5 Collector Dark Current vs. Ambient Temperature

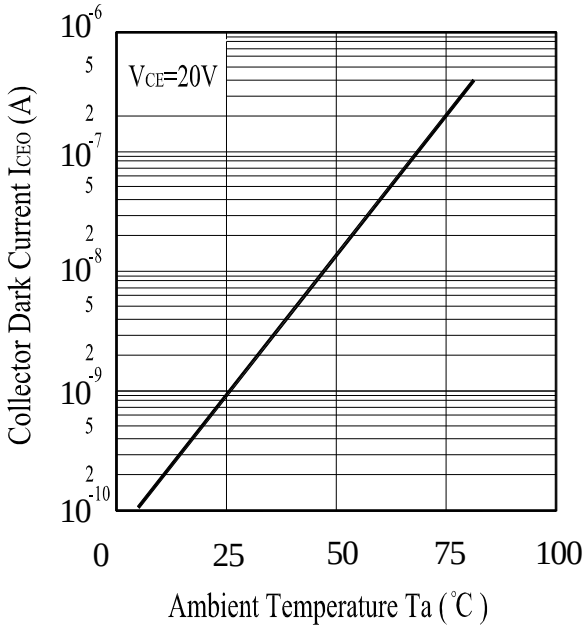
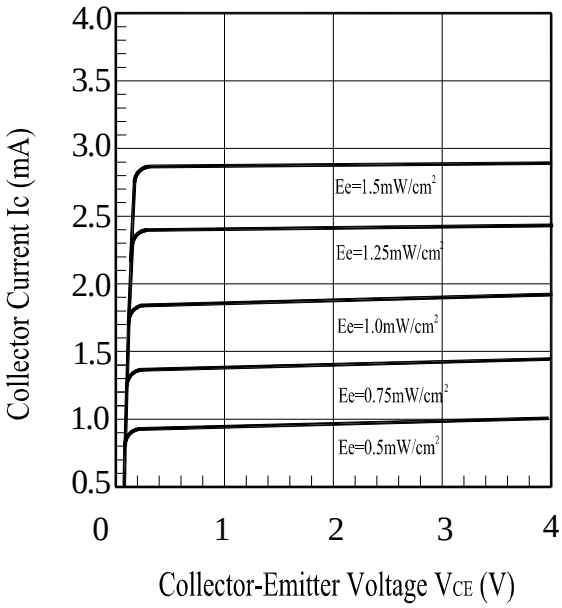


Fig.6 Collector Current vs. Collector-Emitter Voltage

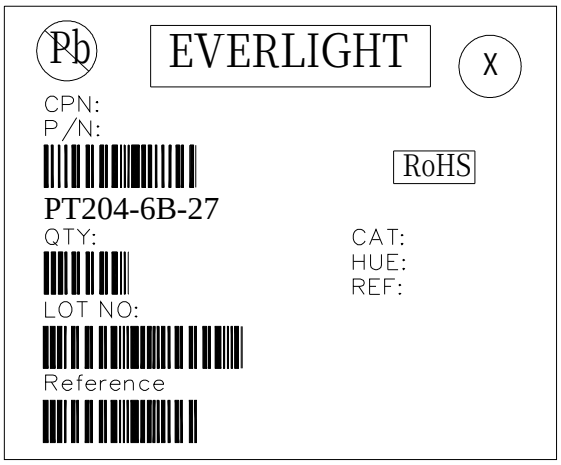


Packing Quantity Specification

1.1000PCS/1Bag，4Bags/1Box

2.10Boxes/1Carton

Label Form Specification



CPN: Customer’s Production Number
P/N : Production Number
QTY: Packing Quantity
CAT: Ranks
HUE: Peak Wavelength
REF: Reference
LOT No: Lot Number
X: Month
Reference: Identify Label Number

Notes

1. Above specification may be changed without notice. EVERLIGHT will reserve authority on material change for above specification.
2. When using this product, please observe the absolute maximum ratings and the instructions for using outlined in these specification sheets. EVERLIGHT assumes no responsibility for any damage resulting from use of the product which does not comply with the absolute maximum ratings and the instructions included in these specification sheets.
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